

# isc Silicon NPN Power Transistor

### **DESCRIPTION**

- · Collector-Emitter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub> = 60V(Min.)
- · Low Saturation Voltage
- Complement to Type BD798
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

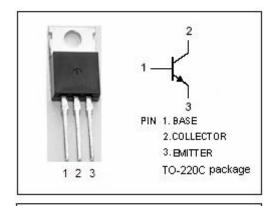
 Designed for a wide variety of medium-power switching and amplifier applications, such as series and shunt regulators and driver and output stages of high-fidelity amplifiers.

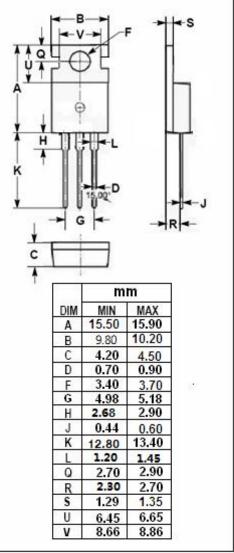


SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	8	А
I <sub>B</sub>	Base Current-Continuous	3	Α
Pc	Collector Power Dissipation $T_c$ =25 $^{\circ}$ C	65	W
T <sub>j</sub>	Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub>	Storage Ttemperature Range	-55~150	$^{\circ}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	1.92	°C/W	







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**BD797** 

## **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 30mA; I <sub>B</sub> = 0	60			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			1	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 2V			1.6	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 60V; I <sub>E</sub> = 0			0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 2V	40			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 2V	25			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.25A; V <sub>CE</sub> = 10V, f <sub>test</sub> = 1MHz	3			MHz

# **NOTICE:**

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